



# 88CXX

CMOS IC

## BUILT-IN DELAY CIRCUIT HIGH-PRECISION VOLTAGE DETECTOR

### DESCRIPTION

The UTC **88CXX** series is a high-precision voltage detector developed and foundry using CMOS process. The detection voltage is fixed internally, with an accuracy of  $\pm 2.0\%$ . The CMOS output is available. Besides, **88CXX** can easily delay a release signal by attachment of an external capacitor with built-in delay circuit.

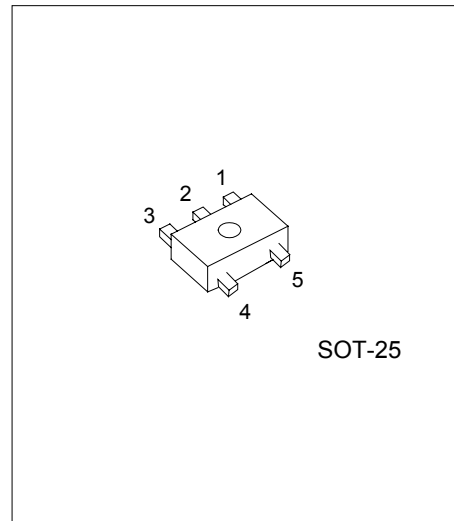
### FEATURES

- \* High-precision detection voltage:  $\pm 2.0\%$
- \* Hysteresis characteristics: 5% typ
- \* Ultra-low current consumption satisfied various detection voltage, 1.0  $\mu$  A typ. ( $V_{DD}=2.0V$ ) for 1.4V and 1.2  $\mu$  A typ. ( $V_{DD}=3.5V$ ) for 1.5V.
- \* Available detection voltage from 1.1~6.0V and step by 0.1V.
- \* Low operating voltage based on detection voltage, 0.8~6.0V for 1.4V and 0.95~10V for 1.5V.
- \* Delay time setting by an additional external capacitor.

### ORDERING INFORMATION

Order Number		Package	Packing
Normal	Lead Free		
88Cxx-AF5-R	88CxxL-AF5-R	SOT-25	Tape Reel

xx: Output Voltage, refer to Marking Information.



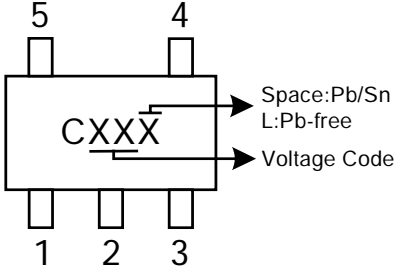
SOT-25

\*Pb-free plating product number: 88CXXL

### PIN CONFIGURATION

PIN NO.	PIN NAME
1	OUT
2	$V_{DD}$
3	$V_{SS}$
4	NC
5	$C_D$

■ MARKING INFORMATION

PACKAGE	VOLTAGE CODE		MARKING
SOT-25	11:1.1V	36:3.6V	
	12:1.2V	37:3.7V	
	13:1.3V	38:3.8V	
	14:1.4V	39:3.9V	
	15:1.5V	40:4.0V	
	16:1.6V	41:4.1V	
	17:1.7V	42:4.2V	
	18:1.8V	43:4.3V	
	19:1.9V	44:4.4V	
	20:2.0V	45:4.5V	
	21:2.1V	46:4.6V	
	22:2.2V	47:4.7V	
	23:2.3V	48:4.8V	
	24:2.4V	49:4.9V	
	25:2.5V	50:5.0V	
	26:2.6V	51:5.1V	
	27:2.7V	52:5.2V	
	28:2.8V	53:5.3V	
	29:2.9V	54:5.4V	
	30:3.0V	55:5.5V	
	31:3.1V	56:5.6V	
	32:3.2V	57:5.7V	
	33:3.3V	58:5.8V	
	34:3.4V	59:5.9V	
	35:3.5V	60:6.0V	

■ ABSOLUTE MAXIMUM RATINGS (Ta=25 , unless otherwise specified.)

PARAMETER		SYMBOL	RATINGS	UNIT
Power Supply Voltage	1.4V	V <sub>DD</sub> -V <sub>SS</sub>	8	V
	1.5V		12	
C <sub>D</sub> terminal Input Voltage		V <sub>CD</sub>	V <sub>SS</sub> -0.3 ~ V <sub>DD</sub> +0.3	V
Output Voltage		V <sub>OUT</sub>	V <sub>SS</sub> -0.3 ~ V <sub>DD</sub> +0.3	V
Output Current		I <sub>OUT</sub>	50	mA
Power Dissipation		P <sub>D</sub>	150	mW
Operating Temperature		T <sub>OPR</sub>	-40 ~ +85	
Storage Temperature		T <sub>STG</sub>	-40 ~ +150	

■ ELECTRICAL CHARACTERISTICS (Ta=25 , unless otherwise specified.)

PARAMETER		SYMBOL	TEST CIRCUIT	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Detection Voltage		-V <sub>DET</sub>	1		-V <sub>DET</sub> ×0.98	-V <sub>DET</sub>	-V <sub>DET</sub> ×1.02	V	
Hysteresis Width		V <sub>HYS</sub>	1		-V <sub>DET</sub> ×0.03	-V <sub>DET</sub> ×0.05	-V <sub>DET</sub> ×0.08	V	
Operating Voltage	1.4V	V <sub>DD</sub>	1		0.8		6.0	V	
	1.5V			0.95	10.0				
Current Consumption	1.1V ~ 1.4V	I <sub>SS</sub>	2	V <sub>DD</sub> =2.0V		1.0	2.5	μA	
	1.5V ~ 2.6V			V <sub>DD</sub> =3.5V		1.2	3.0		
	2.7V ~ 3.9V			V <sub>DD</sub> =4.5V		1.3	3.3		
	4.0V ~ 5.4V			V <sub>DD</sub> =6.0V		1.5	3.8		
	5.5V ~ 6.0V			V <sub>DD</sub> =7.5V		1.6	4.2		
Output Current	1.1V ~ 1.4V	I <sub>OUT</sub>	3	Nch V <sub>DS</sub> =0.5V	V <sub>DD</sub> =0.95V	0.03	0.25	mA	
					V <sub>DD</sub> =1.20V	0.23	0.50		
	V <sub>DD</sub> =1.20V				0.23	0.50			
	V <sub>DD</sub> =2.40V				1.60	3.70			
	V <sub>DD</sub> =1.20V				0.23	0.50			
	V <sub>DD</sub> =2.40V				1.60	3.70			
	1.5V ~ 2.6V			4	Pch(CMOS output) V <sub>DS</sub> =0.5V	V <sub>DD</sub> =4.8V	0.36		0.62
						V <sub>DD</sub> =4.8V	0.36		0.62
						V <sub>DD</sub> =4.8V	0.36		0.62
						V <sub>DD</sub> =6.0V	0.46		0.75
						V <sub>DD</sub> =8.4V	0.59		0.96
						V <sub>DD</sub> =8.4V	0.59		0.96
2.7V ~ 3.9V	4	Pch(CMOS output) V <sub>DS</sub> =0.5V	V <sub>DD</sub> =4.8V	0.36	0.62				
			V <sub>DD</sub> =4.8V	0.36	0.62				
			V <sub>DD</sub> =4.8V	0.36	0.62				
			V <sub>DD</sub> =6.0V	0.46	0.75				
			V <sub>DD</sub> =8.4V	0.59	0.96				
4.0V ~ 5.4V	4	Pch(CMOS output) V <sub>DS</sub> =0.5V	V <sub>DD</sub> =4.8V	0.36	0.62				
			V <sub>DD</sub> =4.8V	0.36	0.62				
			V <sub>DD</sub> =4.8V	0.36	0.62				
			V <sub>DD</sub> =6.0V	0.46	0.75				
			V <sub>DD</sub> =8.4V	0.59	0.96				
5.5V ~ 6.0V	4	Pch(CMOS output) V <sub>DS</sub> =0.5V	V <sub>DD</sub> =4.8V	0.36	0.62				
			V <sub>DD</sub> =4.8V	0.36	0.62				
			V <sub>DD</sub> =4.8V	0.36	0.62				
			V <sub>DD</sub> =6.0V	0.46	0.75				
			V <sub>DD</sub> =8.4V	0.59	0.96				
Delay Time	1.1V ~ 1.4V	td	5	V <sub>DD</sub> =4.5V, C <sub>D</sub> =4.7nF	4.95	6.6	8.25	ms	
	1.5V ~ 2.6V			V <sub>DD</sub> =4.5V, C <sub>D</sub> =4.7nF	4.95	6.6	8.25		
	2.7V ~ 3.9V			V <sub>DD</sub> =4.5V, C <sub>D</sub> =4.7nF	4.95	6.6	8.25		
	4.0V ~ 5.4V			V <sub>DD</sub> =7.0V, C <sub>D</sub> =4.7nF	3	4	5		
	5.5V ~ 6.0V			V <sub>DD</sub> =7.0V, C <sub>D</sub> =4.7nF	3	4	5		

## ■ ELECTRICAL CHARACTERISTICS(Cont.)

PARAMETER	SYMBOL	TEST CIRCUIT	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Temperature Characteristic of $-V_{DET}$	$\frac{\Delta-V_{DET}}{\Delta T_a}$	1	$-V_{DET} = 1.1V$		$\pm 0.19$	$\pm 0.57$	mV/
			$-V_{DET} = 1.2V$		$\pm 0.20$	$\pm 0.60$	
			$-V_{DET} = 1.3V$		$\pm 0.22$	$\pm 0.66$	
			$-V_{DET} = 1.4V$		$\pm 0.24$	$\pm 0.72$	
			$-V_{DET} = 1.5V$		$\pm 0.18$	$\pm 0.54$	
			$-V_{DET} = 1.6V$		$\pm 0.19$	$\pm 0.57$	
			$-V_{DET} = 1.7V$		$\pm 0.20$	$\pm 0.60$	
			$-V_{DET} = 1.8V$		$\pm 0.21$	$\pm 0.63$	
			$-V_{DET} = 1.9V$		$\pm 0.22$	$\pm 0.66$	
			$-V_{DET} = 2.0V$		$\pm 0.24$	$\pm 0.72$	
			$-V_{DET} = 2.1V$		$\pm 0.25$	$\pm 0.75$	
			$-V_{DET} = 2.2V$		$\pm 0.26$	$\pm 0.78$	
			$-V_{DET} = 2.3V$		$\pm 0.27$	$\pm 0.81$	
			$-V_{DET} = 2.4V$		$\pm 0.28$	$\pm 0.84$	
			$-V_{DET} = 2.5V$		$\pm 0.29$	$\pm 0.87$	
			$-V_{DET} = 2.6V$		$\pm 0.31$	$\pm 0.93$	
			$-V_{DET} = 2.7V$		$\pm 0.32$	$\pm 0.96$	
			$-V_{DET} = 2.8V$		$\pm 0.33$	$\pm 0.99$	
			$-V_{DET} = 2.9V$		$\pm 0.34$	$\pm 1.02$	
			$-V_{DET} = 3.0V$		$\pm 0.35$	$\pm 1.05$	
			$-V_{DET} = 3.1V$		$\pm 0.36$	$\pm 1.08$	
			$-V_{DET} = 3.2V$		$\pm 0.38$	$\pm 1.14$	
			$-V_{DET} = 3.3V$		$\pm 0.39$	$\pm 1.17$	
			$-V_{DET} = 3.4V$		$\pm 0.40$	$\pm 1.20$	
			$-V_{DET} = 3.5V$		$\pm 0.41$	$\pm 1.23$	
			$-V_{DET} = 3.6V$		$\pm 0.42$	$\pm 1.26$	
			$-V_{DET} = 3.7V$		$\pm 0.44$	$\pm 1.32$	
			$-V_{DET} = 3.8V$		$\pm 0.45$	$\pm 1.35$	
			$-V_{DET} = 3.9V$		$\pm 0.46$	$\pm 1.38$	
			$-V_{DET} = 4.0V$		$\pm 0.47$	$\pm 1.41$	
			$-V_{DET} = 4.1V$		$\pm 0.48$	$\pm 1.44$	
			$-V_{DET} = 4.2V$		$\pm 0.49$	$\pm 1.47$	
			$-V_{DET} = 4.3V$		$\pm 0.51$	$\pm 1.53$	
			$-V_{DET} = 4.4V$		$\pm 0.52$	$\pm 1.56$	
			$-V_{DET} = 4.5V$		$\pm 0.53$	$\pm 1.59$	
			$-V_{DET} = 4.6V$		$\pm 0.54$	$\pm 1.62$	
$-V_{DET} = 4.7V$		$\pm 0.55$	$\pm 1.65$				
$-V_{DET} = 4.8V$		$\pm 0.56$	$\pm 1.68$				
$-V_{DET} = 4.9V$		$\pm 0.58$	$\pm 1.74$				
$-V_{DET} = 5.0V$		$\pm 0.59$	$\pm 1.77$				
$-V_{DET} = 5.1V$		$\pm 0.60$	$\pm 1.80$				
$-V_{DET} = 5.2V$		$\pm 0.61$	$\pm 1.83$				
$-V_{DET} = 5.3V$		$\pm 0.62$	$\pm 1.86$				
$-V_{DET} = 5.4V$		$\pm 0.64$	$\pm 1.92$				
$-V_{DET} = 5.5V$		$\pm 0.65$	$\pm 1.95$				
$-V_{DET} = 5.6V$		$\pm 0.66$	$\pm 1.98$				
$-V_{DET} = 5.7V$		$\pm 0.67$	$\pm 2.01$				
$-V_{DET} = 5.8V$		$\pm 0.68$	$\pm 2.04$				
$-V_{DET} = 5.9V$		$\pm 0.69$	$\pm 2.07$				
$-V_{DET} = 6.0V$		$\pm 0.71$	$\pm 2.13$				

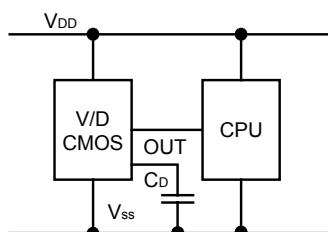
■ DETECTION VOLTAGE RANGE vs HYSTERESIS WIDTH

DETECTION VOLTAGE RANGE (V)	HYSTERESIS WIDTH $V_{HYS}$ TYP (V)	DETECTION VOLTAGE RANGE (V)	HYSTERESIS WIDTH $V_{HYS}$ TYP (V)
1.1V±2.0%	0.055	3.6V±2.0%	0.180
1.2V±2.0%	0.060	3.7V±2.0%	0.185
1.3V±2.0%	0.065	3.8V±2.0%	0.190
1.4V±2.0%	0.070	3.9V±2.0%	0.195
1.5V±2.0%	0.075	4.0V±2.0%	0.200
1.6V±2.0%	0.080	4.1V±2.0%	0.205
1.7V±2.0%	0.085	4.2V±2.0%	0.210
1.8V±2.0%	0.090	4.3V±2.0%	0.215
1.9V±2.0%	0.095	4.4V±2.0%	0.220
2.0V±2.0%	0.100	4.5V±2.0%	0.225
2.1V±2.0%	0.105	4.6V±2.0%	0.230
2.2V±2.0%	0.110	4.7V±2.0%	0.235
2.3V±2.0%	0.115	4.8V±2.0%	0.240
2.4V±2.0%	0.120	4.9V±2.0%	0.245
2.5V±2.0%	0.125	5.0V±2.0%	0.250
2.6V±2.0%	0.130	5.1V±2.0%	0.255
2.7V±2.0%	0.135	5.2V±2.0%	0.260
2.8V±2.0%	0.140	5.3V±2.0%	0.265
2.9V±2.0%	0.145	5.4V±2.0%	0.270
3.0V±2.0%	0.150	5.5V±2.0%	0.275
3.1V±2.0%	0.155	5.6V±2.0%	0.280
3.2V±2.0%	0.160	5.7V±2.0%	0.285
3.3V±2.0%	0.165	5.8V±2.0%	0.290
3.4V±2.0%	0.170	5.9V±2.0%	0.295
3.5V±2.0%	0.175	6.0V±2.0%	0.300

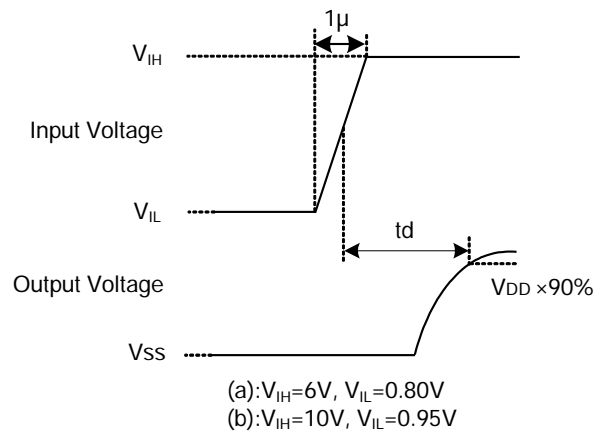
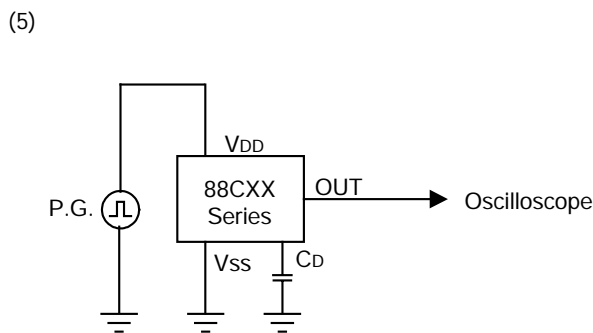
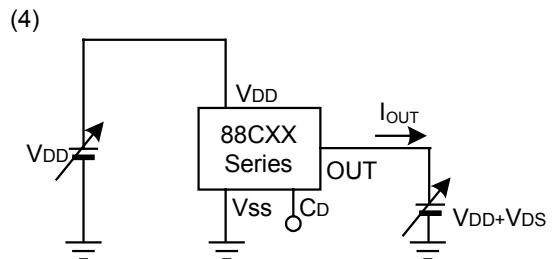
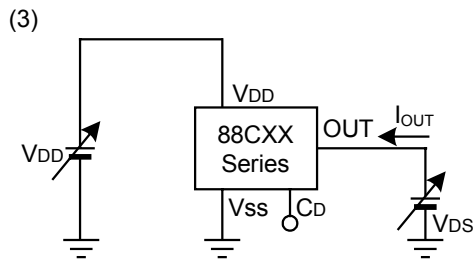
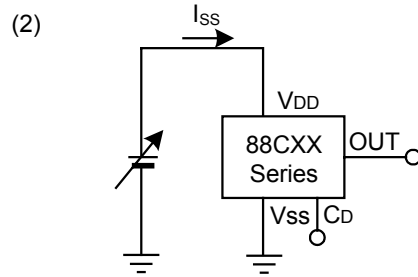
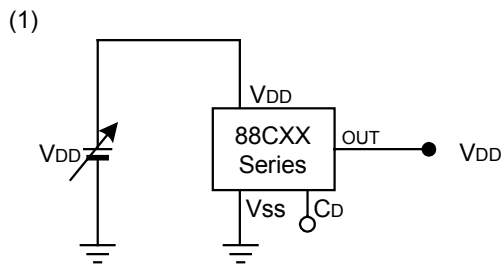
■ OUTPUT CONFIGURATIONS

Implementation	CMOS
With different power supplies	No
With active low reset CPUs	Yes
With active high reset CPUs	No
With voltage divider variable resistors	No

Example with one power supply



## ■ TEST CIRCUITS



## ■ TECHNICAL TERMS

### 1. Detection voltage ( $-V_{DET}$ )

The detection voltage  $-V_{DET}$  is the voltage at which the output switches to low. This detection voltage varies slightly among products of the same type. The variation of voltages between the specified minimum [ $(-V_{DET})_{min.}$ ] and maximum [ $(-V_{DET})_{max.}$ ] values is called the detection voltage range (See Figure 1).

Example: For the  $-V_{DET}=1.5V$ , detection voltage lies in the range of 1.470 ( $-V_{DET}$ ) 1.530. This means that  $-V_{DET}$  is 1.470 in a product while  $-V_{DET}$  is 1.530 in another of the same  $-V_{DET}=1.5V$ .

### 2. Release voltage ( $+V_{DET}$ )

The release voltage  $+V_{DET}$  is the voltage at which the output returns (is "released") to high. This release voltage varies slightly among products of the same type. The variation of voltages between the specified minimum [ $(+V_{DET})_{min.}$ ] and maximum [ $(+V_{DET})_{max.}$ ] values is called the release voltage range (See Figure 2).

Example: For the  $-V_{DET}=1.5V$ , the release voltage lies in the range of 1.514 ( $+V_{DET}$ ) 1.652. This means that  $+V_{DET}$  is 1.514 in a product while  $+V_{DET}$  is 1.652 in another of the same  $-V_{DET}=1.5V$ .

Remark: Although the detection voltage and release voltage overlap in the range of 1.514 V ~ 1.530 V,  $+V_{DET}$  will always be larger than  $-V_{DET}$ .

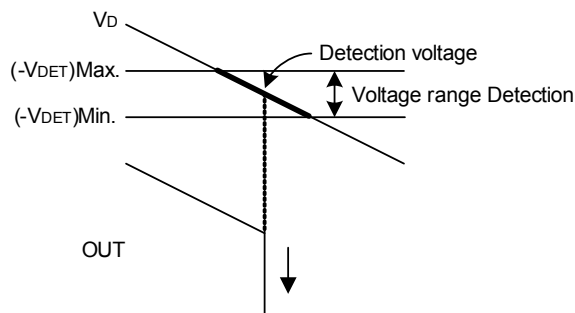


Figure 1

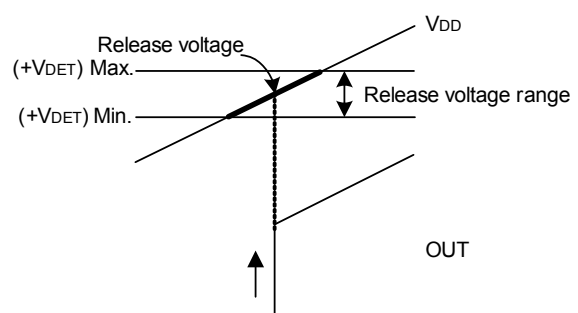


Figure 2 ( $C_D=0F$ )

### 3. Hysteresis width ( $V_{HYS}$ )

The hysteresis width is the voltage difference between the detection voltage and the release voltage ( $B-A=V_{HYS}$  in Figure 7). By giving a device hysteresis, trouble such as noise at the input is avoided.

### 4. Delay time ( $t_d$ )

The delay time is a time that the input voltage to  $V_{DD}$  terminal exceeds the release voltage ( $+V_{DET}$ ) and then the output of the OUT terminal inverts. The delay time can be changed by the additional external capacitor  $C_D$ .

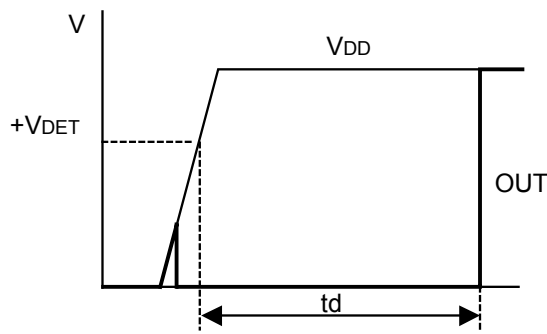


Figure 3

5. Through-type current

Through-type current refers to the current which flows instantaneously, at the time of detection and release of a voltage detector. Through-type current is large in CMOS output devices.

6. Oscillation

In applications where a resistor is connected to the voltage detector input, in the CMOS active low products for example, the through-type current generated when the output goes from low to high (release) causes a voltage drop equal to [through-type current]  $\times$  [input resistance] across the resistor. When the resultant input voltage drops below the detection voltage  $-V_{DET}$ , the output voltage returns to its low level. In this state, the through-type current and its resultant voltage drop have disappeared, and the output goes back from low to high. A through-type current is again generated, a voltage drop appears, and the process repeats. This unstable condition is referred to as oscillation.

■ STANDARD CIRCUIT

Connect directly the  $C_D$  capacitor for delay between  $C_D$  and  $V_{SS}$  terminals

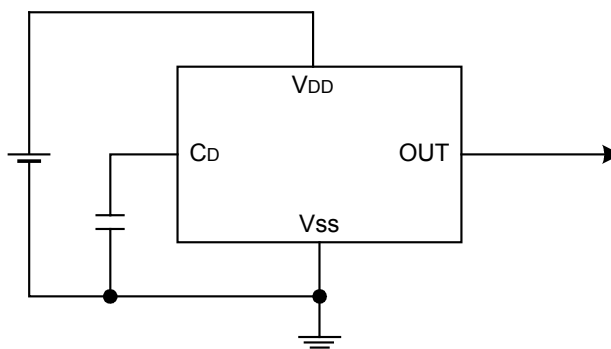


Figure 5



■ OPERATION

1. Basic operation: CMOS active low output

- (1) When power supply voltage  $V_{DD}$  is greater than the release voltage  $+V_{DET}$ , the Nch transistor is OFF and the Pch transistor ON, causing  $V_{DD}$  (high) to appear at the output.
- (2) When power supply voltage  $V_{DD}$  goes below  $+V_{DET}$ , the output maintains the power supply voltage level, as long as  $V_{DD}$  remains above the detection voltage  $-V_{DET}$ . When  $V_{DD}$  does fall below  $-V_{DET}$  (A in Figure 7), the Nch transistor goes ON the Pch transistor goes OFF, and  $V_{SS}$  appears at the output.
- (3) When  $V_{DD}$  falls below the minimum operating voltage, the output becomes undefined. However, output will revert to  $V_{DD}$  if a pull-up has been employed.
- (4)  $V_{SS}$  will again be output when  $V_{DD}$  rises above the minimum operating voltage.  $V_{SS}$  will continue to be output even when  $V_{DD}$  surpasses  $-V_{DET}$ , as long as it does not exceed the release voltage  $+V_{DET}$ .
- (5) When  $V_{DD}$  rises above  $+V_{DET}$  (B in Figure 7), the Nch transistor goes OFF the Pch transistor goes ON, and  $V_{DD}$  appears at the output. Then  $V_{DD}$  at the OUT terminal appears with delay time ( $t_d$ ) due to delay circuit.

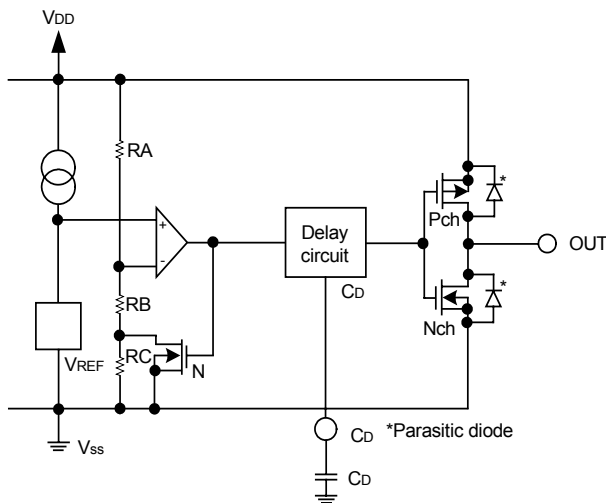


Figure 6

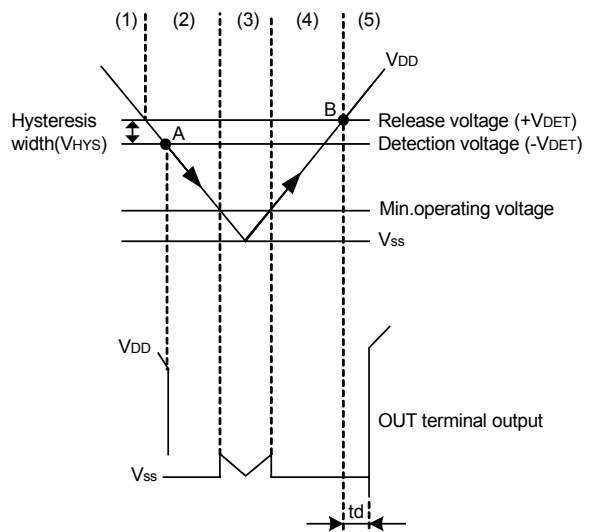


Figure 7

2. Delay circuit

The delay circuit outputs the signal delayed from the release voltage ( $+V_{DET}$ ) point of the power voltage  $V_{DD}$  rising. The output signal is not delayed when the  $V_{DD}$  goes down the detection voltage ( $-V_{DET}$ ) or less. (See Figure 7).

The delay time ( $t_d$ ) is determined by the time constant of the built-in constant current (approx. 100nA in the case of products with detection voltage of 1.5V or more, approx. 570nA in the case of products with detection voltage of 1.4V or less) and the attached external capacitor ( $C_D$ ), and calculated from the following formula.

$$t_d \text{ (ms)} = \text{Delay factor} \times C_D \text{ (nF)}$$

Delay factor: (25 )

Products with detection voltage of 1.4V or less: Min.0.57, Typ.0.77, Max.0.96

Products with detection voltage of 1.5V or more: Min.3.8, Typ. 5.1, Max.6.4

**Cautions**

\*The open of C<sub>D</sub> terminal may cause double pulses shown in Figure 8 at release. If the double pulses cause a trouble, attach 10pF or larger capacitor to the C<sub>D</sub> terminal. Do not apply the voltage to the C<sub>D</sub> terminal.

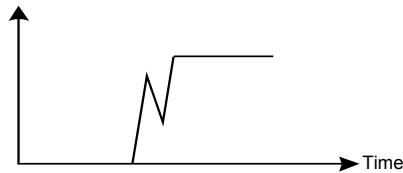


Figure 8

\*Layout the print circuit board not to apply or flow out the current to/from the C<sub>D</sub> terminal. Doing not so may cause inaccurate delay time.

\*Use an external capacitor, C<sub>D</sub> of which leakage current can be ignored for the built-in constant-current value. A leakage current may cause an error of delay time. Also, a leakage current over the built-in constant-current causes unrelease status.

3. Other characteristics

(1) Temperature characteristic of detection voltage.

The temperature characteristics of the detection voltage are expressed by the oblique line parts in Figure 9.

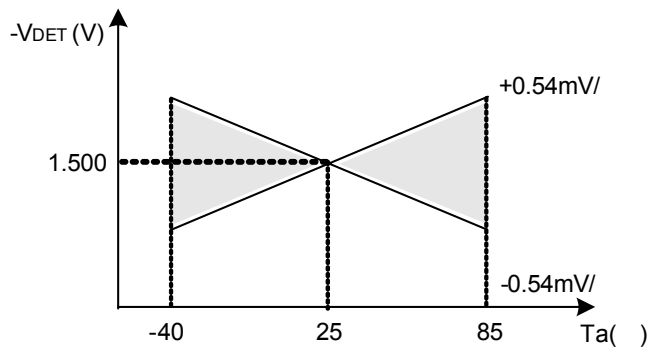


Figure 9

(2) Temperature characteristics of release voltage

The temperature factor (  $\frac{+V_{DEF}}{Ta}$  ) of the release voltage is calculated by the temperature factor of the detection voltage as follows:

$$\frac{\Delta + V_{DET}}{\Delta Ta} = \frac{+V_{DET}}{-V_{DET}} \times \frac{\Delta - V_{DET}}{\Delta Ta}$$

The temperature factor of the release voltage has a same sign characteristics as the temperature factor of the detection voltage.

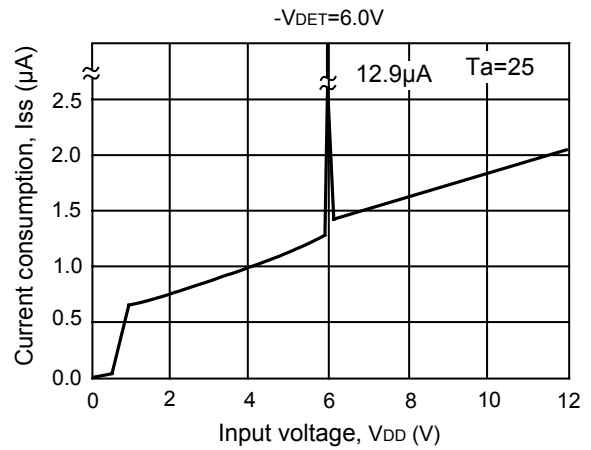
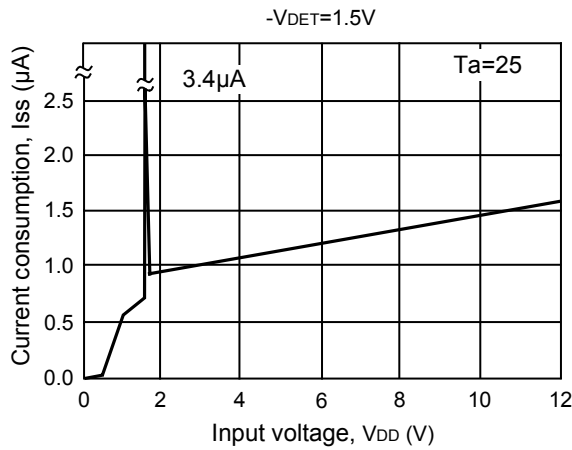
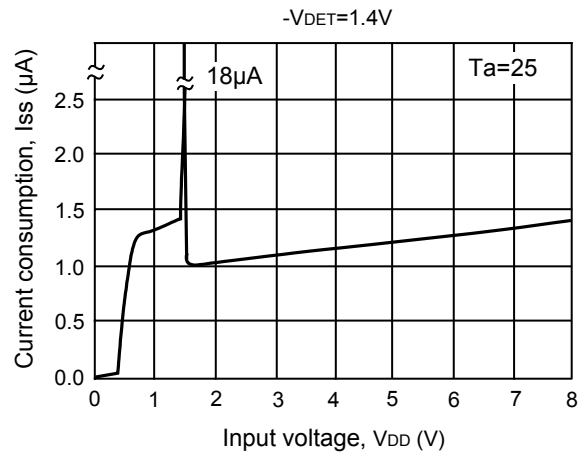
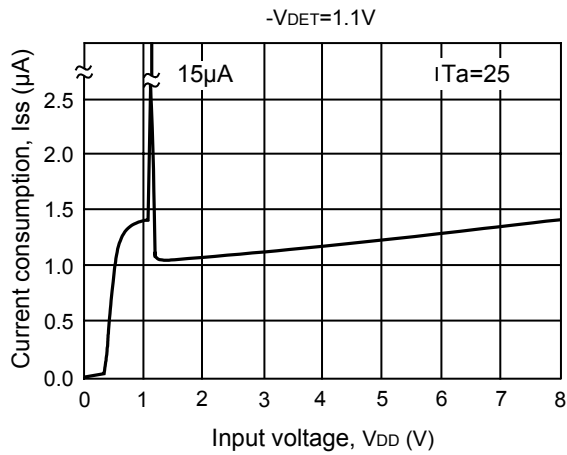
(3) Temperature characteristics of hysteresis voltage

The temperature characteristics of hysteresis voltage (  $\frac{+V_{DEF}}{Ta} - \frac{-V_{DEF}}{Ta}$  ) is calculated as follows:

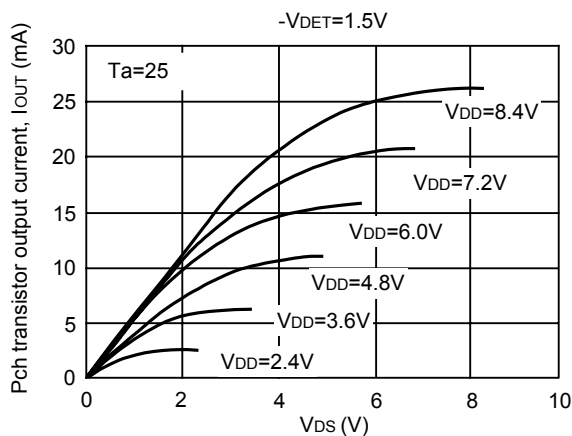
$$\frac{\Delta + V_{\text{DET}}}{\Delta T_a} - \frac{\Delta - V_{\text{DET}}}{\Delta T_a} = \frac{V_{\text{HYS}}}{-V_{\text{DET}}} \times \frac{\Delta - V_{\text{DET}}}{\Delta T_a}$$

■ TYPICAL PERFORMANCE CHARACTERISTICS

(1) Current consumption – Input voltage

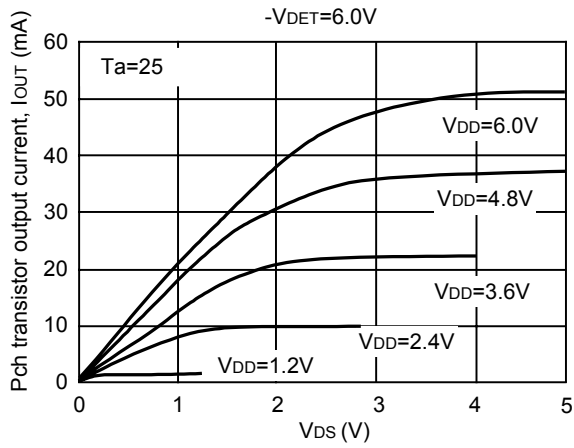


(2) Pch transistor output current -  $V_{DS}$

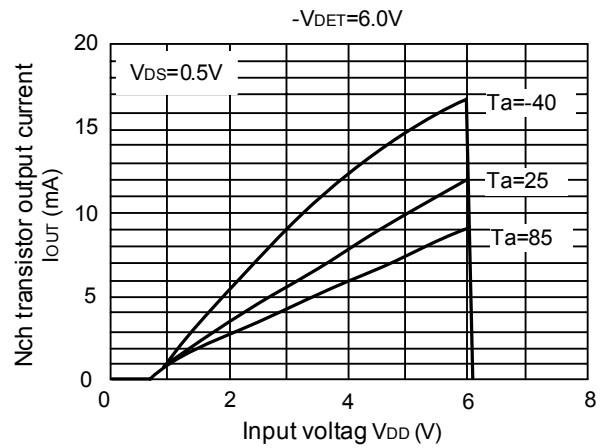
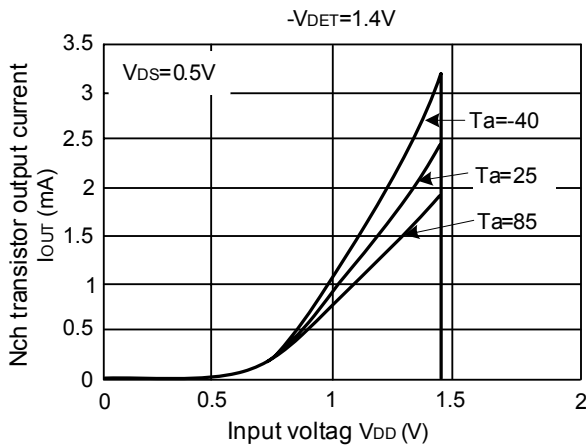


■ TYPICAL PERFORMANCE CHARACTERISTICS (Cont.)

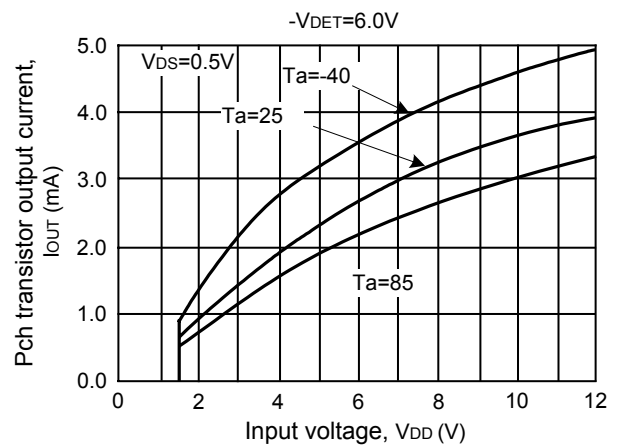
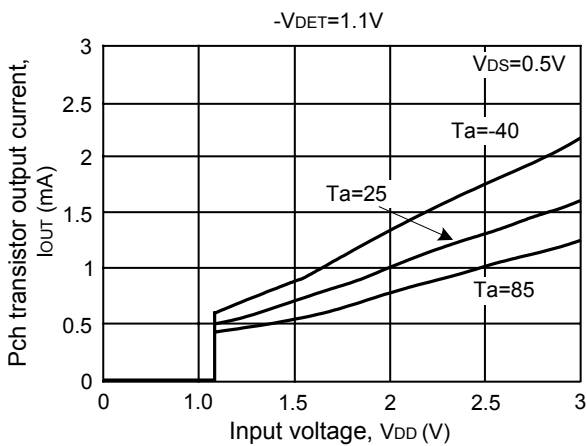
(3) Nch transistor output current ( $I_{OUT}$ ) –  $V_{DS}$



(4) Nch transistor output current – Input voltage

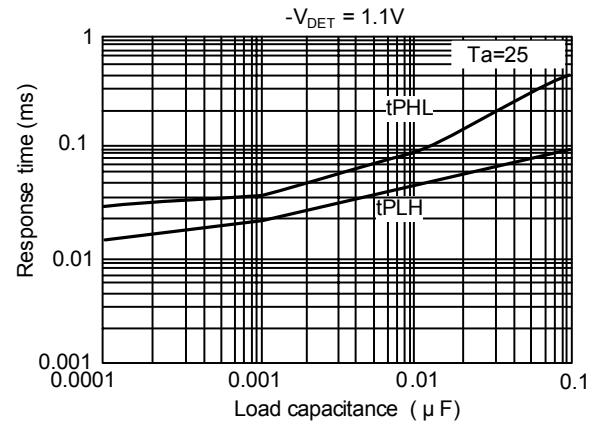
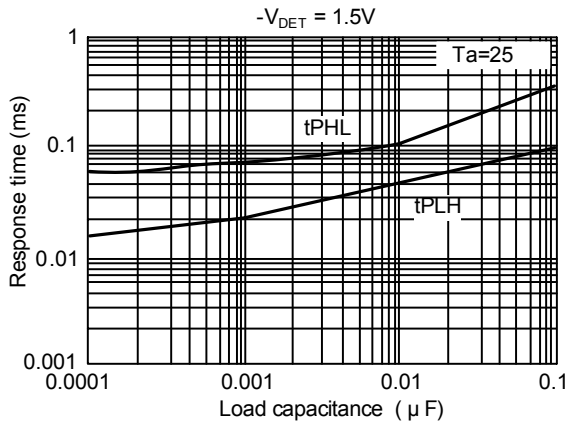
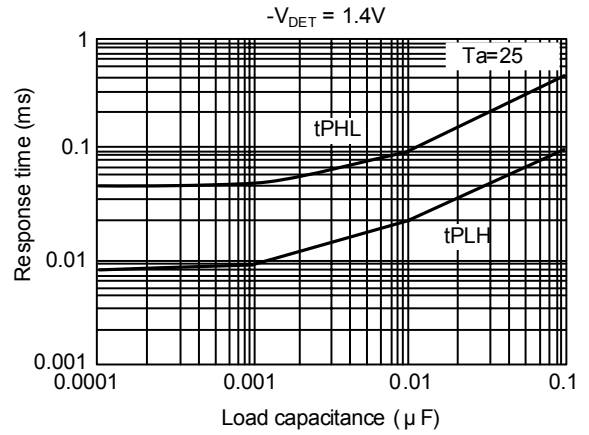
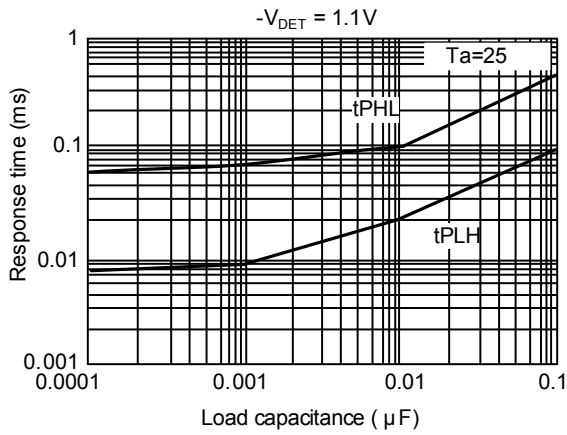


(5) Pch transistor output current – Input voltage

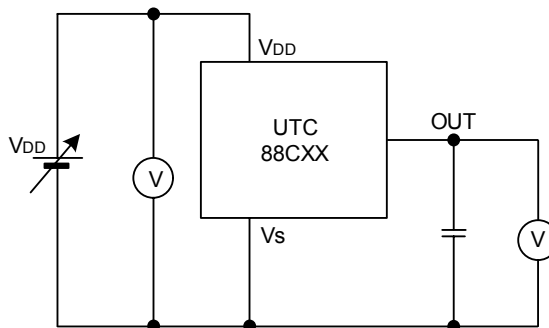


■ TYPICAL PERFORMANCE CHARACTERISTICS (Cont.)

(6) Dynamic response (CD : Open)



Response Time Measure Circuit





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